

# SEMICONDUCTOR TECHNICAL DATA

### KRC101S~ KRC106S

EPITAXIAL PLANAR NPN TRANSISTOR

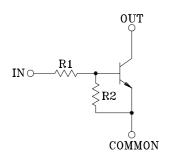
SWITCHING APPLICATION.

INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

#### **FEATURES**

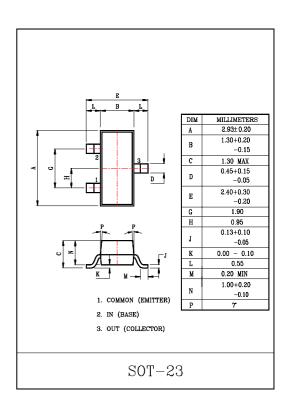
- · With Built-in Bias Resistors.
- · Simplify Circuit Design.
- · Reduce a Quantity of Parts and Manufacturing Process.

#### EQUIVALENT CIRCUIT



#### BIAS RESISTOR VALUES

DIAS RESISTOR VALUES							
TYPE NO.	$R1(k\Omega)$	$R2(k\Omega)$					
KRC101S	4.7	4.7					
KRC102S	10	10					
KRC103S	22	22					
KRC104S	47	47					
KRC105S	2.2	47					
KRC106S	4.7	47					



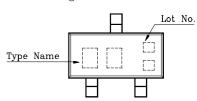
#### MAXIMUM RATINGS (Ta=25℃)

CHARACTERIST	`IC	SYMBOL	RATING	UNIT
Output Voltage	KRC101S ~106S	Vo	50	V
	KRC101S	VI	20, -10	
	KRC102S		30, -10	
T.,	KRC103S		40, -10	V
Input Voltage	KRC104S		40, -10	V
	KRC105S		12, -5	
	KRC106S		20, -5	
Output Current		Io	100	mA
Power Dissipation	KRC101S	$P_{\mathrm{D}}$	200	mW
Junction Temperature	~106S	T <sub>j</sub>	150	°C
Storage Temperature Range		$T_{\mathrm{stg}}$	-55 <b>~</b> 150	°C

MARK SPEC

TYP	Έ	KRC101S	KRC102S	KRC103S	KRC104S	KRC105S	KRC106S
MAI	RK	NA	NB	NC	ND	NE	NF





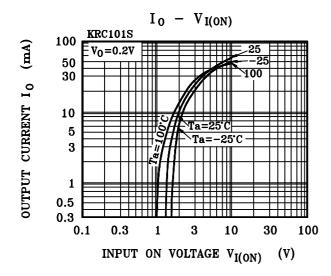
#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

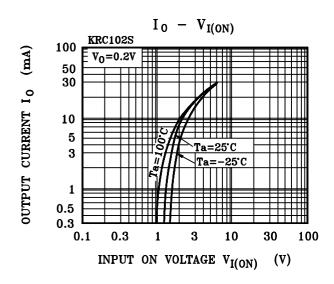
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Cut-off Current	KRC101S~106S	$I_{O(OFF)}$	$V_{O}=50V, \ V_{I}=0$	-	-	500	nA
	KRC101S		V <sub>O</sub> =5V, I <sub>O</sub> =10mA	30	55	-	
	KRC102S			50	80	-	
DC Current Gain	KRC103S	$G_{\mathrm{I}}$		70	120	-	
De current dam	KRC104S		V0-3V, 10-10IIIA	80	200	_	
	KRC105S			80	200	_	
	KRC106S			80	200	-	
Output Voltage	KRC101S~106S	$V_{O(ON)}$	$I_O=10$ mA, $I_I=0.5$ mA	-	0.1	0.3	V
	KRC101S	V <sub>I(ON)</sub>	$V_{O}$ =0.2 $V$ , $I_{O}$ =5 $mA$	-	1.5	2.0	V
	KRC102S			-	1.8	2.4	
I (NI)	KRC103S			-	2.1	3.0	
Input Voltage (ON)	KRC104S			-	2.8	5.0	
	KRC105S			-	0.8	1.1	
	KRC106S			-	0.9	1.3	
Least Vetters (OFF)	KRC101S~104S	77	V <sub>O</sub> =5V, I <sub>O</sub> =0.1mA	1.0	1.2	-	<b>T</b> 7
Input Votlage (OFF)	KRC105S~106S	$V_{\rm I(OFF)}$		0.5	0.65	-	V
Transition Frequency	KRC101S~106S	f <sub>T</sub> *	$V_O=10V$ , $I_O=5mA$	_	200	-	MHz
	KRC101S		$ m V_I$ =5 $ m V$	-		1.8	
Input Current	KRC102S	$I_{\rm I}$		-	-	0.88	mA
	KRC103S			-	-	0.36	
	KRC104S			-	-	0.18	
	KRC105S			-	-	3.6	
	KRC106S			-	-	1.8	

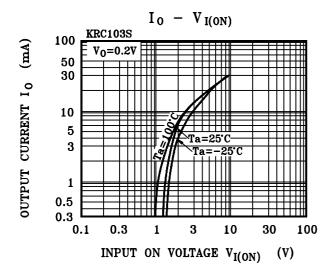
Note: \*Characteristic of Transistor Only

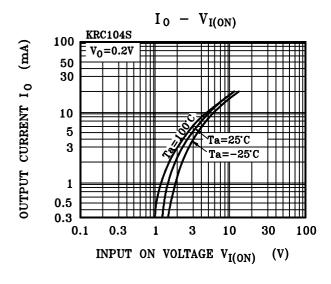
#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

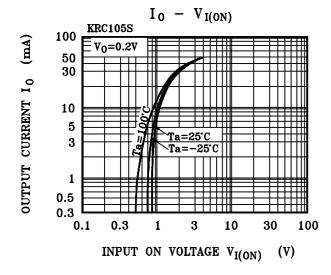
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
	Rise	KRC101S			-	0.03	-	
		KRC102S			-	0.05	-	
		KRC103S			-	0.12	-	μS
	Time	KRC104S	$t_{\mathrm{r}}$		_	0.22	-	
		KRC105S			_	0.01	_	
		KRC106S			_	0.03	-	
	Storage Time	KRC101S	t <sub>stg</sub>	$V_{O}=5V$ $V_{IN}=5V$ $R_{L}=1k\Omega$	_	2.0	-	
		KRC102S			_	2.0	-	
Switching		KRC103S			_	2.0	-	
Time		KRC104S			_	2.0	-	
		KRC105S			_	2.0	-	
		KRC106S			_	2.0	-	
	Fall Time	KRC101S	$\mathbf{t}_{\mathrm{f}}$		-	0.12	_	
		KRC102S			-	0.36	-	
		KRC103S			-	0.35	-	
		KRC104S			_	0.6	-	
		KRC105S			=	0.1	-	
		KRC106S			_	0.19	-	

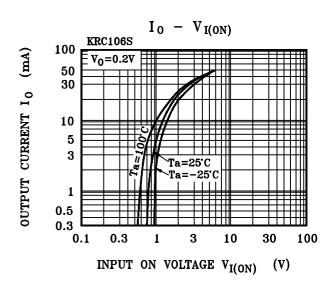


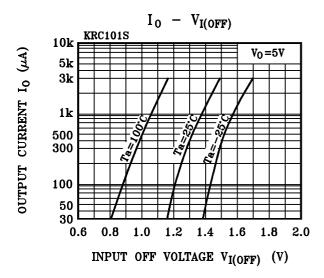


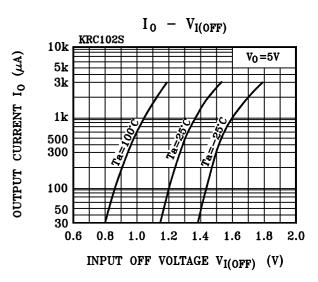


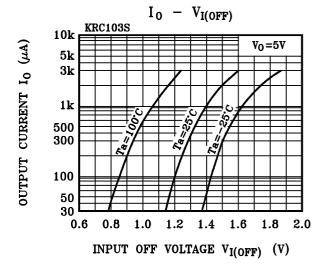


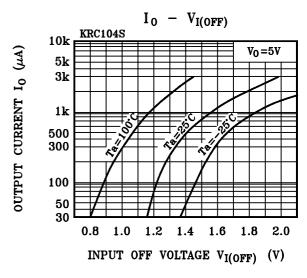


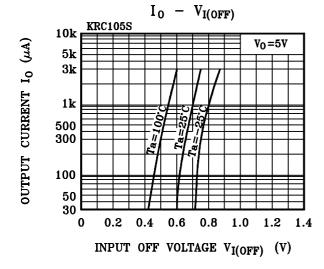


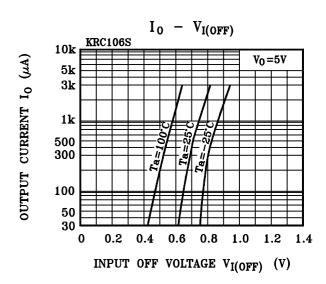


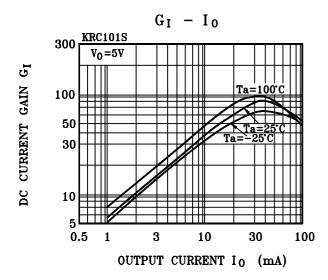


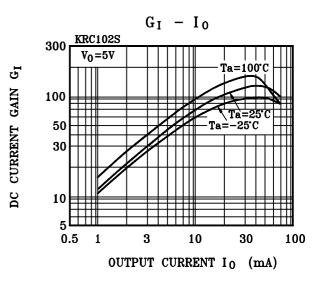


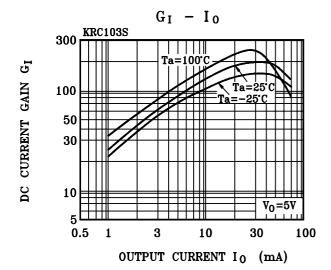


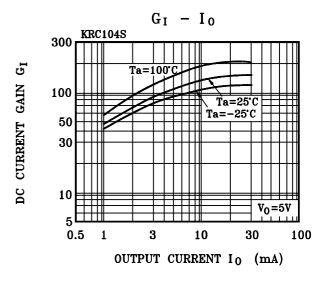


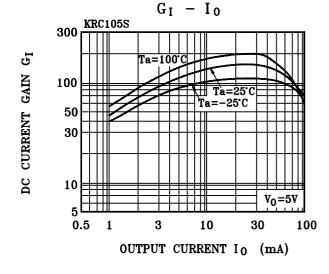


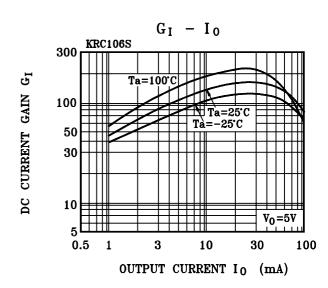














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